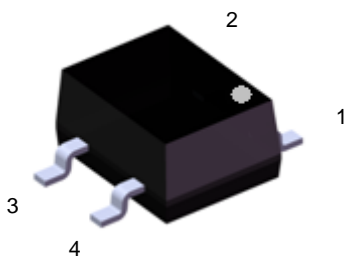


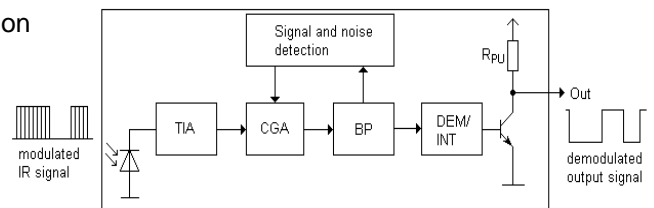
### Infrared Remote Control Receiver Module EAIRMKA0



#### Pin Configuration

1. GND
2. GND
3. Out
4. V<sub>CC</sub>

#### Block Diagram



#### Features

- high immunity against TFT and plasma backlight
- high immunity against ambient light
- suppresses common IR protocols
- Min burst length: 3 cycles
- Low operating voltage and low power consumption
- long reception range and wide viewing angle
- Pb free and RoHS compliant
- appearance package: black
- Compliance with EU REACH
- Compliance Halogen Free .(Br <900 ppm ,Cl <900 ppm , Br+Cl < 1500 ppm)

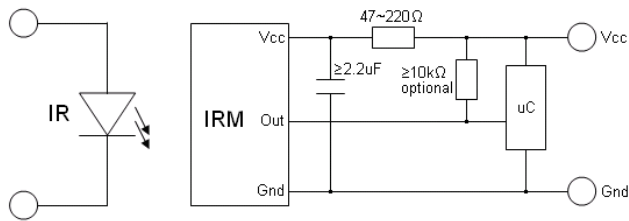
#### Description

- The device is a miniature type infrared receiver which have been developed and designed by using the latest IC technology.
- The photo diode and preamplifier are assembled onto a lead frame and molded into an epoxy package which operates as an IR filter.
- The demodulated output signal can directly be decoded by a microprocessor.

#### Applications

- 3D TV shutter glasses

### Application Circuit



The RC Filter must be connected as close as possible to Vcc and GND pins.

### Parts Table

Model No.	Carrier Frequency
EAIRMKAO	20 kHz

### Absolute Maximum Ratings (T<sub>a</sub>=25°C)

Parameter	Symbol	Rating	Unit
Supply Voltage	Vcc	6	V
Operating Temperature	Topr	-20 ~ +80	°C
Storage Temperature	Tstg	-40 ~ +85	°C
Soldering Temperature <sup>*1</sup>	Tsol	260	°C

<sup>\*1</sup> 4mm from mold body for less than 5 seconds

**Electro-Optical Characteristics (Ta=25°C, Vcc=3V)**

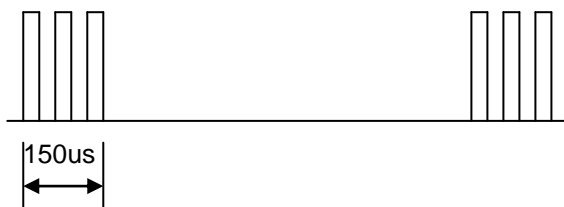
Parameter	Symbol	MIN.	TYP.	MAX.	Unit	Condition
Current consumption	I <sub>CC</sub>	0.4	0.6	0.8	mA	No input signal
Supply voltage	V <sub>CC</sub>	2.5	-	5.5	V	
Reception range	L <sub>0</sub>	8	-	-	m	See chapter ,Test method'
	L <sub>45</sub>	5	-	-		
Half angle(horizontal)	φ <sub>h</sub>	-	±60	-	deg	
Half angle(vertical)	φ <sub>v</sub>	-	±60	-	deg	
Low level pulse width	T <sub>L</sub>	100	250	450	μs	Test signal fig.1
High level output voltage	V <sub>OH</sub>	V <sub>CC</sub> -0.4	-	-	V	Open circuit
Low level output voltage	V <sub>OL</sub>	-	0.2	0.5	V	I <sub>SINK</sub> ≤ 2mA
Internal pull up resistor	R <sub>PU</sub>	-	52	-	kΩ	

### Test method

The specified electro-optical characteristics are valid under the following conditions.

1. Measurement environment  
 A place without extreme light reflections.
2. External light  
 The environment contains an ordinary, white fluorescent lamp without high frequency modulation. The color temperature is 2856K and the illumination at the IR receiver is less than 10 Lux ( $E_v \leq 10\text{Lux}$ ).
3. the radiant intensity of the standard transmitter is 100mWsr
4. The measurement system is shown in Fig.-3

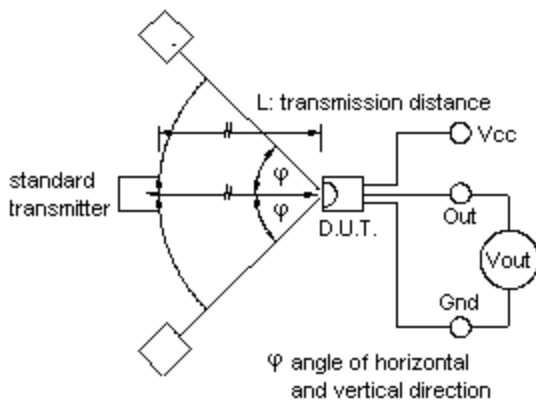
Fig.-1 Transmitter Wave Form



D.U.T output Pulse

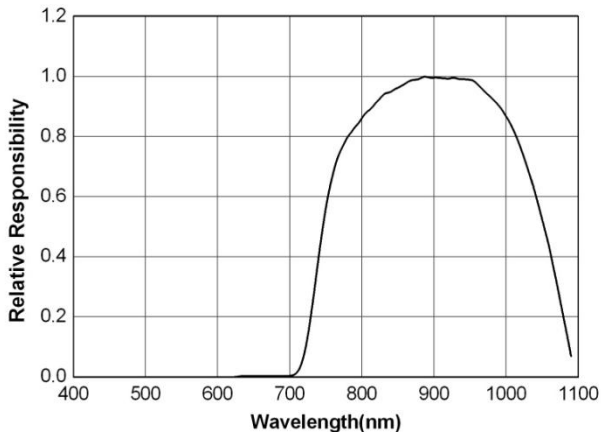


Fig.-2 Measuring System

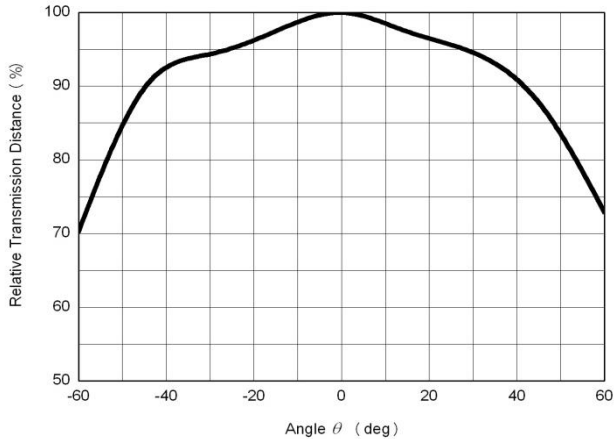


**Typical Performance Curves**

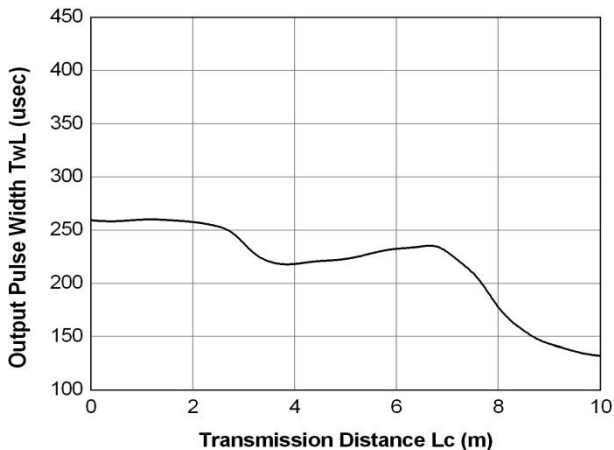
**Fig.-4 Relative Responsibility vs. Wavelength**



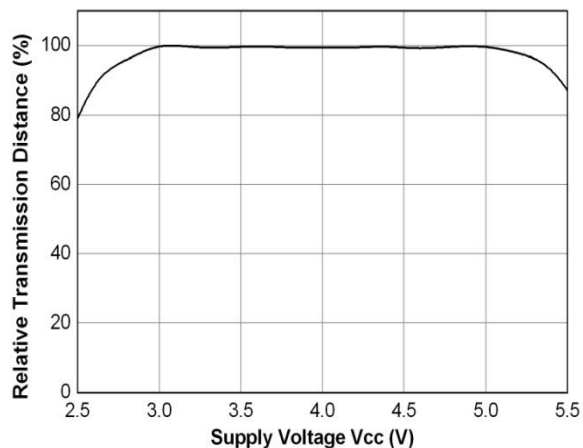
**Fig.-5 Relative Transmission Distance vs. Direction**



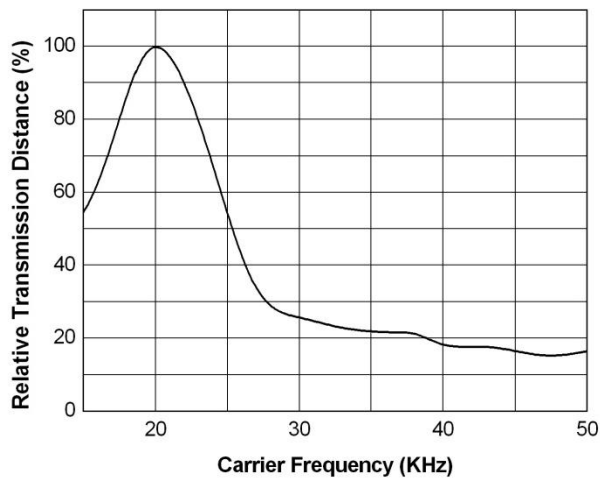
**Fig.-6 Output Pulse Width vs. Transmission Distance**



**Fig.-7 Relative Transmission Distance vs. Supply Voltage**

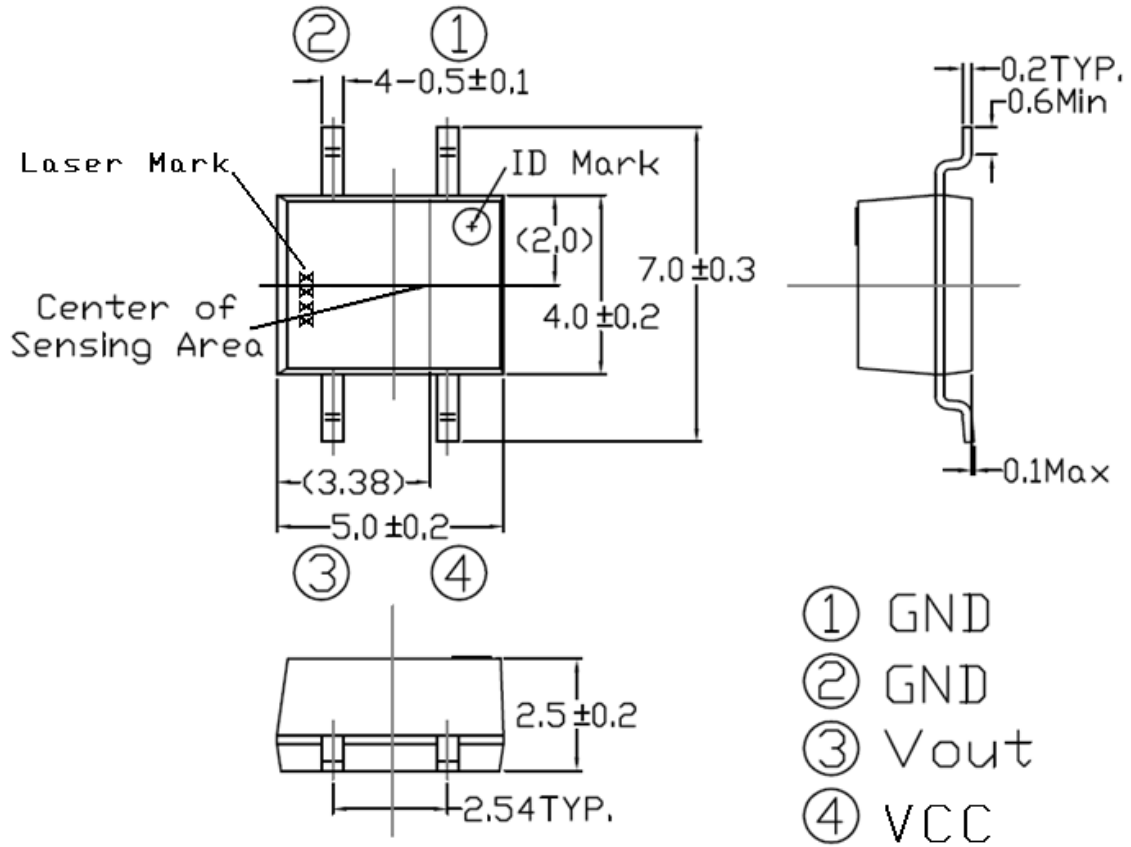


**Fig.-8 Relative Transmission Distance vs. Carrier Frequency**

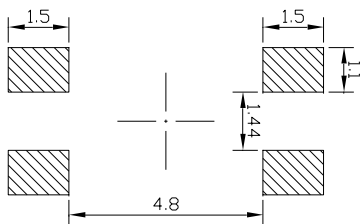


**Package Dimensions**

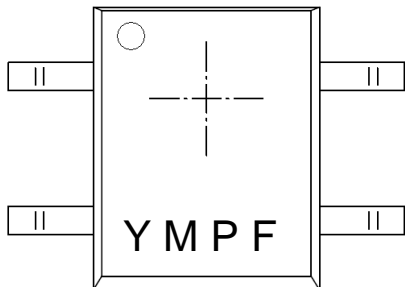
(Dimensions in mm)



**Recommended pad layout for surface mount leadform**



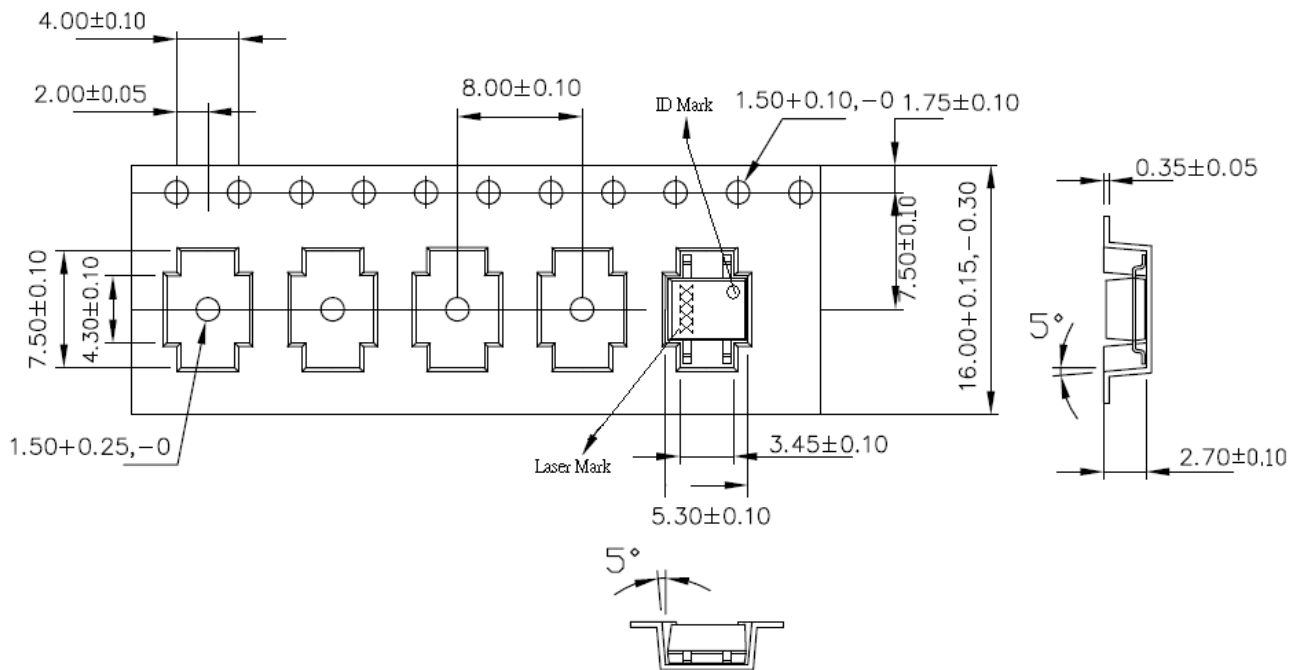
**Device Marking**



**Notes**

- Y denotes Year code
- M denotes month code
- P denotes device number
- F denotes frequency

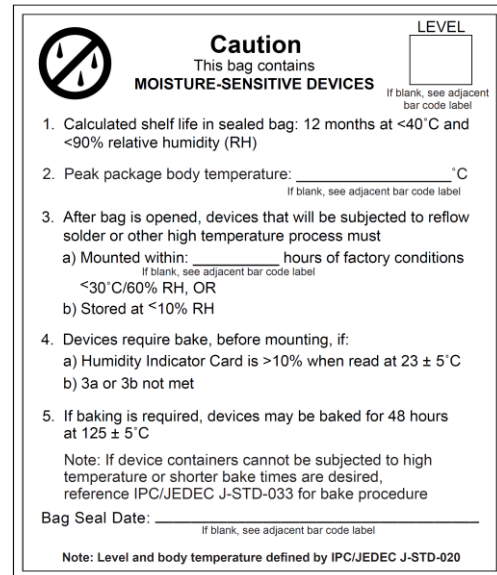
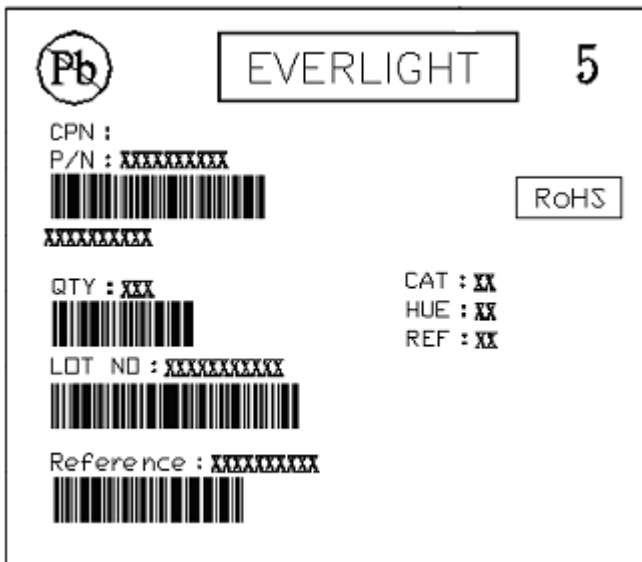
**Tape & Reel Packing Specifications**



**Packing Quantity**

- 1000 pcs / Reel
- 5 Reels / Carton

### Label format



Moisture Classification-storage and used condition label

### Recommended method of storage

The following are general recommendations for moisture sensitive level (MSL) 4 storage and use:

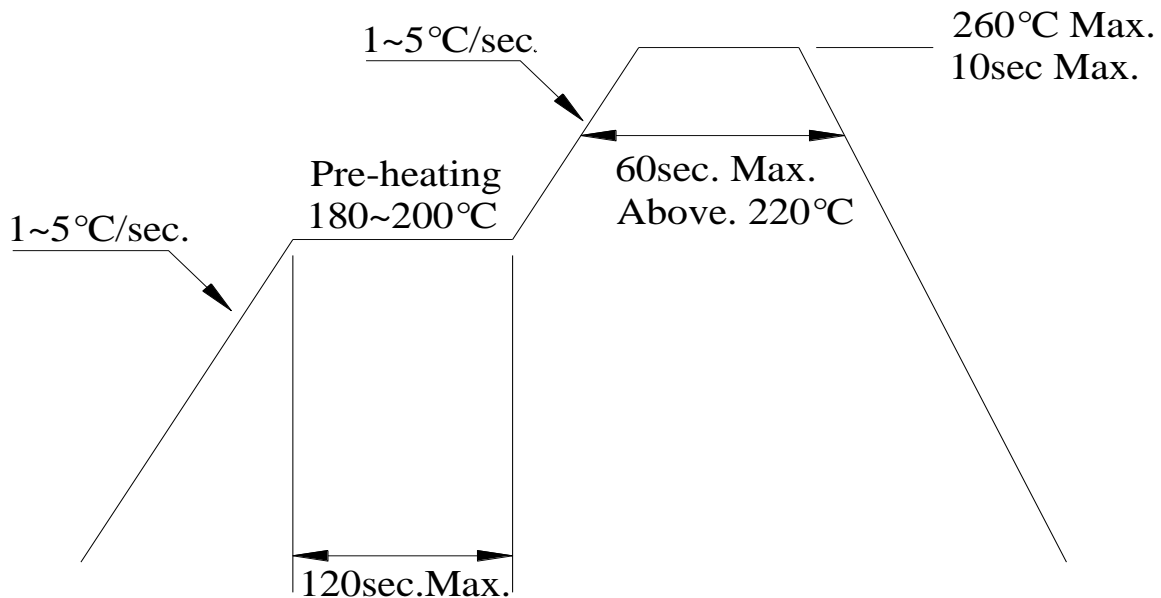
1. Shelf life in sealed bag from the bag seal date: 12 months at < 40 °C and < 90% relative humidity (RH)
2. After bag is opened, devices that will be subjected to reflow solder or other high temperature process must mounted within 72 hours of factory conditions < 30 °C/60%RH.
3. If the moisture absorbent material (silica gel) has faded away or the IRM has exceeded the storage time. Baking treatment is required, refer to IPC/JEDEC J-STD-033 for bake procedure or recommend the conditions: 60±5°C for 96 hours.

### ESD Precaution

Proper storage and handing procedures should be followed to prevent ESD damage to the devices especially when they are removed from the Anti-static bag. Electro-Static Sensitive Devices warning labels are on the packing.



## Solder Reflow Temperature Profile



Note:

1. Reflow soldering should not be done more than two times.
2. When soldering, do not put stress on the IRM device during heating.
3. After soldering, do not warp the circuit board.

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